



PNP POWER SILICON TRANSISTOR

Qualified per MIL-PRF-19500/535

Qualified Levels: JAN, JANTX, and JANTXV

DESCRIPTION

This high speed transistor is rated at 5 amps and is military qualified up to a JANTXV level. This TO-59 isolated package is available with a 180 degree lead orientation. Microsemi also offers numerous other products to meet higher and lower power voltage regulation applications.

Important: For the latest information, visit our website http://www.microsemi.com.

FEATURES

- JEDEC registered 2N5003 and 2N5005.
- Internal metallurgical bond option available.
- JAN, JANTX, and JANTXV, qualification per MIL-PRF-19500/535 available.
- RoHS compliant versions available (commercial grade only).



Marking may vary.

TO-59 (TO-210AA) Isolated Package

APPLICATIONS / BENEFITS

- Fast switching capable 0.5 μs rise time.
- High frequency response.
- TO-59 case with Isolated terminals.
- Class 3B to ESD per MIL-STD-750 Method 1020.

MAXIMUM RATINGS

Parameters/Test Conditions	Symbol	Value	Unit
Junction and Storage Temperature	T_J and T_{STG}	-65 to +200	°C
Thermal Resistance Junction-to-Ambient	$R_{\Theta JA}$	88	°C/W
Thermal Resistance Junction-to-Case	R _{eJC}	3.0	°C/W
Collector Current	Ic	5.0	Α
	I _C ⁽³⁾	10	
Collector-Emitter Voltage	V_{CEO}	80	V
Collector-Base Voltage	V_{CBO}	100	V
Emitter-Base Voltage	V_{EBO}	5.5	V
Steady-State Power Dissipation @ $T_A = +25^{\circ}C^{(1)}$	P _D	2.0	W
$^{\circ}$ T _C = +25°C (2)		58	

Notes:

- 1. Derate linearly 11.4 mW/ $^{\circ}$ C for T_A > +25 $^{\circ}$ C.
- 2. Derate linearly 331 mW/°C for $T_C > +25$ °C.
- 3. This value applies for PW \leq 8.3 ms, duty cycle \leq 1%.

MSC - Lawrence

6 Lake Street, Lawrence, MA 01841 1-800-446-1158 (978) 620-2600 Fax: (978) 689-0803

MSC - Ireland

Gort Road Business Park, Ennis, Co. Clare, Ireland Tel: +353 (0) 65 6840044 Fax: +353 (0) 65 6822298

Website:

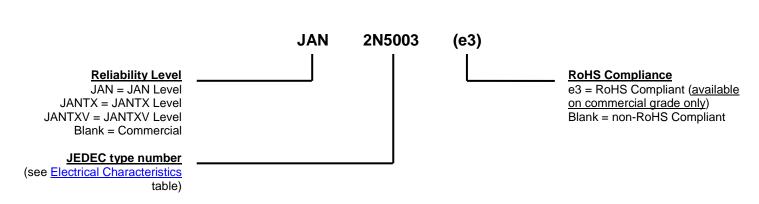
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MECHANICAL and PACKAGING

- CASE: Nickel Plated.
- TERMINALS: Solder Dip over Nickel Plating. RoHS compliant Matte/Tin available on commercial grade only.
- MARKING: Manufacturer's ID, Date Code, Part Number, BeO.
- POLARITY: See Package Outline Drawing on last page.
- See <u>Package Dimensions</u> on last page.

PART NOMENCLATURE



SYMBOLS & DEFINITIONS				
Symbol	Definition			
C_obo	Common-base open-circuit output capacitance.			
I _{CEO}	Collector cutoff current, base open.			
I _{CES}	Collector emitter cutoff current, circuit between base and emitter.			
I _{EBO}	Emitter cutoff current, collector open.			
h _{FE}	Common-emitter static forward current transfer ratio.			
V_{CEO}	Collector-emitter voltage, base open.			
V_{CBO}	Collector-emitter voltage, emitter open.			
V_{EBO}	Emitter-base voltage, collector open.			



ELECTRICAL CHARACTERISTICS @ $T_C = 25^{\circ}C$ unless otherwise noted.

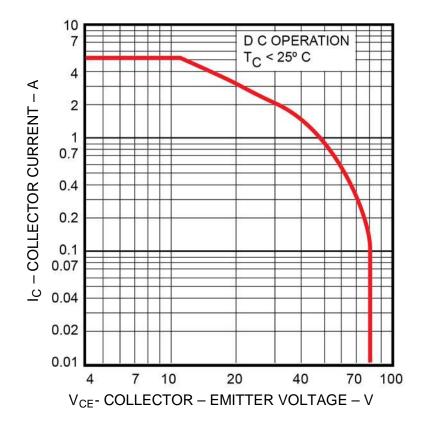
Characteristic		Symbol	Min.	Max.	Unit
OFF CHARACTERISTICS					
OFF CHARACTERISTICS Collector-Emitter Breakdown Voltage		1		1	
		$V_{(BR)CEO}$	80		V
I _C = 100 mA Collector-Emitter Cutoff Current					
$V_{CE} = 40 \text{ V}, I_{B} = 0$		I _{CEO}		50	μΑ
Collector-Emitter Cutoff Current					
$V_{CE} = 60 \text{ V}, V_{BE} = 0$		I _{CES}		1.0	μΑ
$V_{CE} = 100 \text{ V}, V_{BE} = 0$ $V_{CE} = 100 \text{ V}, V_{BE} = 0$		CES		1.0	mA
Emitter-Base Cutoff Current					
V _{BF} = 4.0 V, I _C = 0		I _{EBO}		1.0	μΑ
$V_{BE} = 5.5 \text{ V}, I_{C} = 0$		EBO		1.0	mA
		I	-1	1	
ON CHARACTERISTICS					
Forward-Current Transfer Ratio					
$I_C = 50 \text{ mA}, V_{CE} = 5.0 \text{ V}$	2N5003	h _{FE}	20		
$I_C = 2.5 \text{ A}, V_{CE} = 5.0 \text{ V}$			30	90	
$I_C = 5.0 \text{ A}, V_{CE} = 5.0 \text{ V}$			20		
$I_C = 50 \text{ mA}, V_{CE} = 5.0 \text{ V}$	2N5005		50	200	
$I_C = 2.5 \text{ A}, V_{CE} = 5.0 \text{ V}$			70 40	200	
$I_C = 5.0 \text{ A}, V_{CE} = 5.0 \text{ V}$			40		
Base-Emitter Voltage Non-saturated		V _{BE}			
$V_{CE} = 5.0 \text{ V}, I_{C} = 2.5 \text{ A}$		∧ RF		1.45	V
Collector-Emitter Saturation Voltage					l
$I_C = 2.5 \text{ A}, I_B = 250 \text{ mA}$		V _{CE(sat)}		0.75	V
I _C = 5.0 A, I _B = 500 mA				1.5	
Base-Emitter Saturation Voltage				4 45	.,,
$I_C = 2.5 \text{ A}, I_B = 250 \text{ mA}$		V _{BE(sat)}		1.45 2.2	V
$I_C = 5.0 \text{ A}, I_B = 500 \text{ mA}$				2.2	
DYNAMIC CHARACTERISTICS Common Emitter Small-Signal Short-Circuit		1			1
Forward Current Transfer Ratio	2N5003	h _{fe}	20		
$I_C = 100 \text{ mA}, V_{CE} = 5.0 \text{ V}, f = 1 \text{ kHz}$	2N5005		50		
			+		
Magnitude of Common Emitter Small-Signal Sh Forward Current Transfer Ratio	2N5003	h _{fe}	6.0		
$I_C = 500 \text{ mA}, V_{CE} = 5.0 \text{ V}, f = 10 \text{ MHz}$	2N5005		7.0		
Output Capacitance	2110000		7.0		
$V_{CB} = 10 \text{ V}, I_E = 0, f = 1 \text{ MHz}$		C _{obo}		250	pF
VCB = 10 V, IE = 0, I = 1 IVII IZ				200	
SWITCHING CHARACTERISTICS					
Turn-On Time					
I _C = 5 A; I _{B1} = 500 mA		t _{on}		0.5	μS
Storage Time I _{B2} = -500 mA		t _s	1	1.4	μS
Fall Time $V_{BE(OFF)} = 3.7 \text{ V}$			1	0.5	•
Turn-Off Time		t _f		0.0	μS
R _L = 6 Ohms		t _{off}		1.5	μS
<u>-</u>		U			μο



ELECTRICAL CHARACTERISTICS @ $T_c = 25^{\circ}C$ unless otherwise noted. (continued)

SAFE OPERATING AREA (See Figure below and MIL-STD-750, Test Method 3053)

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DC Tests T_{C} = +25^{\circ}\text{C}, \ V_{CE} = 0, \ t_{P} = 1 \text{ second 1 Cycle} Test 1 V_{CE} = 12 \text{ V}, \ I_{C} = 5 \text{ A} Test 2 V_{CE} = 32 \text{ V}, \ I_{C} = 1.7 \text{ A} Test 3 V_{CE} = 80 \text{ V}, \ I_{C} = 100 \text{ mA}
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Maximum safe operating area



GRAPHS

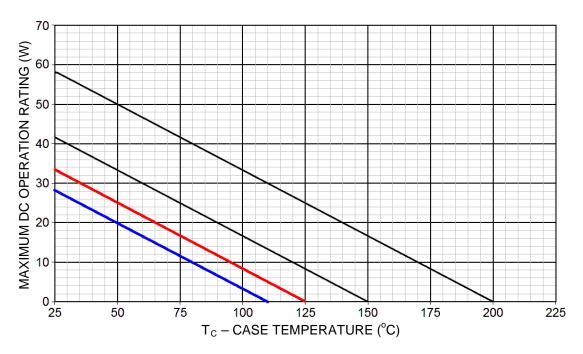


FIGURE 1
Temperature-Power Derating

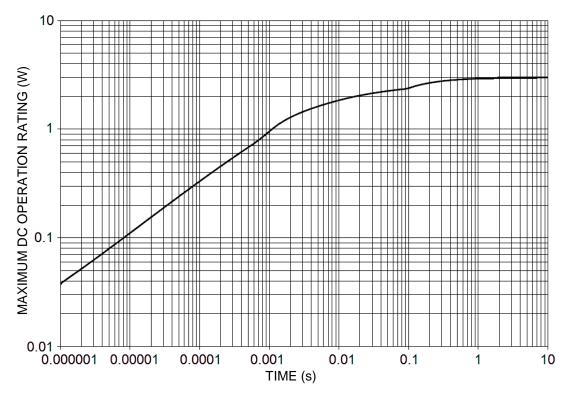
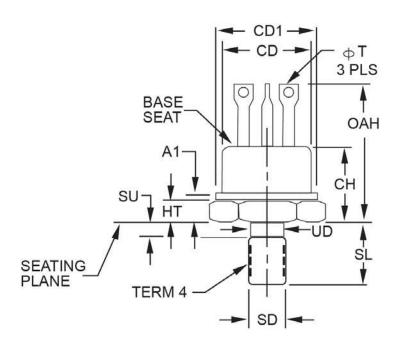
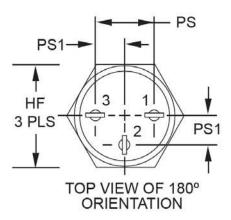


FIGURE 2
Thermal Impedance



PACKAGE DIMENSIONS





NOTES:

- 1. Dimensions are in inches.
- 2. Millimeters are given for general information only.
- 3. See NSB Handbook H28, "Screw-Thread Standards for Federal Services".
- 4. The orientation of the terminals in relation to the hex flats is not controlled.
- 5. All three terminals.
- The case temperature may be measured anywhere on the seating plane within .125 inch (3.18 mm) of the stud.
- 7. Terminal spacing measured at the base seat only.
- 8. This dimension applies to the location of the center line of the terminals.
- 9. Terminal 1, emitter; terminal 2, base; terminal 3, collector. Collector lead is isolated from the case.
- 10. In accordance with ASME Y14.5M, diameters are equivalent to Φx symbology.

	Dimension				
Symbol	Inches		Millimeters		Notes
	Min	Max	Min	Max	
A1		.250		6.35	
CD	.330	.360	8.38	9.14	
CD1	.370	.437	9.40	11.10	
CH	.320	.468	8.13	11.89	
HF	.424	.437	10.77	11.10	
HT	.090	.150	2.29	3.81	
OAH	.575	.763	14.61	19.38	5
PS	.185	.215	4.70	5.46	4, 8
PS1	.090	.110	2.29	2.79	4, 8
SL	.400	.455	10.16	11.56	
SU		.078		1.98	7
T	.040	.065	1.02	1.65	
UD	.155	.189	3.94	4.80	